

MOSFETs Silicon N-channel MOS (U-MOSIV)

TK80F08K3

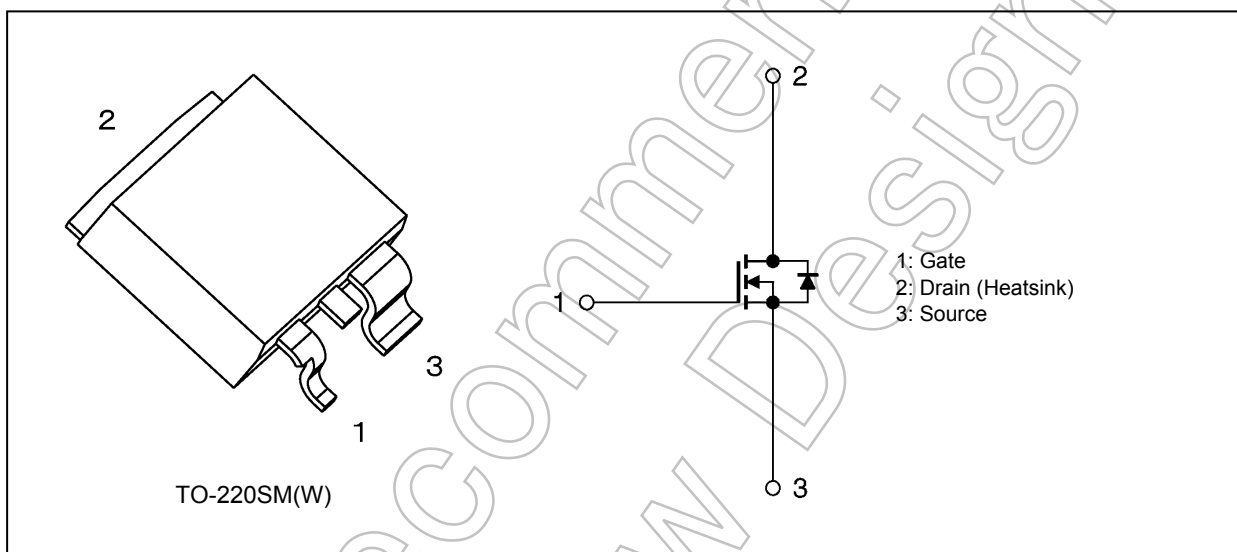
1. Applications

- Switching Voltage Regulators

2. Features

- (1) AEC-Q101 qualified
- (2) Low drain-source on-resistance: $R_{DS(ON)} = 3.4 \text{ m}\Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (3) Low leakage current: $I_{DSS} = 10 \text{ }\mu\text{A}$ (max) ($V_{DS} = 75 \text{ V}$)
- (4) Enhancement mode: $V_{th} = 2.0$ to 4.0 V ($V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$)

3. Packaging and Internal Circuit



Start of commercial production

2012-06

4. Absolute Maximum Ratings (Note) ($T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Rating | Unit |
|--|-----------|------------|------------------|
| Drain-source voltage | V_{DSS} | 75 | V |
| Drain-gate voltage ($R_{GS} = 20\text{k}\Omega$) | V_{DGR} | 75 | |
| Gate-source voltage | V_{GSS} | ± 20 | |
| Drain current (DC) (Note 1) | I_D | 80 | A |
| Drain current (pulsed) (Note 1) | I_{DP} | 320 | |
| Power dissipation ($T_c = 25^\circ\text{C}$) | P_D | 300 | W |
| Single-pulse avalanche energy (Note 2) | E_{AS} | 250 | mJ |
| Avalanche current | I_{AR} | 80 | A |
| Repetitive avalanche energy (Note 3) | E_{AR} | 30 | mJ |
| Channel temperature (Note 4) | T_{ch} | 175 | $^\circ\text{C}$ |
| Storage temperature (Note 4) | T_{stg} | -55 to 175 | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|------------------------------------|----------------|-----|--------------------|
| Channel-to-case thermal resistance | $R_{th(ch-c)}$ | 0.5 | $^\circ\text{C/W}$ |

Note 1: Ensure that the channel temperature does not exceed 175°C .

Note 2: $V_{DD} = 25\text{ V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 58\ \mu\text{H}$, $R_G = 1\ \Omega$, $I_{AR} = 80\text{ A}$

Note 3: Repetitive rating; pulse width limited by maximum channel temperature.

Note 4: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|---------------|---|-----|------|---------|------------------|
| Gate leakage current | I_{GSS} | $V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$ | — | — | ± 1 | μA |
| Drain cut-off current | I_{DSS} | $V_{DS} = 75\text{ V}, V_{GS} = 0\text{ V}$ | — | — | 10 | |
| Drain-source breakdown voltage | $V_{(BR)DSS}$ | $I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$ | 75 | — | — | V |
| Drain-source breakdown voltage (Note 5) | $V_{(BR)DSX}$ | $I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$ | 50 | — | — | |
| Gate threshold voltage | V_{th} | $V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$ | 2.0 | — | 4.0 | |
| Drain-source on-resistance | $R_{DS(ON)}$ | $V_{GS} = 10\text{ V}, I_D = 40\text{ A}$ | — | 3.4 | 4.3 | $\text{m}\Omega$ |

Note 5: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------|-----------|---|-----|------|-----|-------------|
| Input capacitance | C_{iss} | $V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$ | — | 8200 | — | pF |
| Reverse transfer capacitance | C_{rss} | | — | 770 | — | |
| Output capacitance | C_{oss} | | — | 1140 | — | |
| Switching time (rise time) | t_r | See Fig. 6.2.1 | — | 30 | — | ns |
| Switching time (turn-on time) | t_{on} | | — | 55 | — | |
| Switching time (fall time) | t_f | | — | 33 | — | |
| Switching time (turn-off time) | t_{off} | | — | 150 | — | |

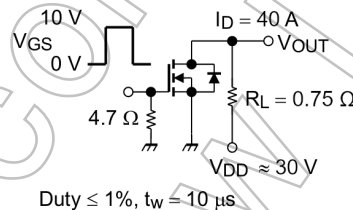


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|---|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | Q_g | $V_{DD} \approx 60\text{ V}, V_{GS} = 10\text{ V}, I_D = 80\text{ A}$ | — | 175 | — | nC |
| Gate-source charge 1 | Q_{gs1} | | — | 40 | — | |
| Gate-drain charge | Q_{gd} | | — | 65 | — | |
| Gate switch charge | Q_{sw} | | — | 80 | — | |

6.4. Source-Drain Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|---|-----|------|------|------|
| Reverse drain current (DC) (Note 6) | I_{DR} | — | — | — | 80 | A |
| Reverse drain current (pulsed) (Note 6) | I_{DRP} | — | — | — | 320 | |
| Diode forward voltage | V_{DSF} | $I_{DR} = 80\text{ A}, V_{GS} = 0\text{ V}$ | — | -0.9 | -1.2 | V |
| Reverse recovery time | t_{rr} | $I_{DR} = 80\text{ A}, V_{GS} = 0\text{ V}$ $dI_{DR}/dt = 50\text{ A}/\mu\text{s}$ | — | 60 | — | ns |
| Reverse recovery charge | Q_{rr} | | — | 60 | — | nC |

Note 6: Ensure that the channel temperature does not exceed 175°C .

7. Marking (Note)

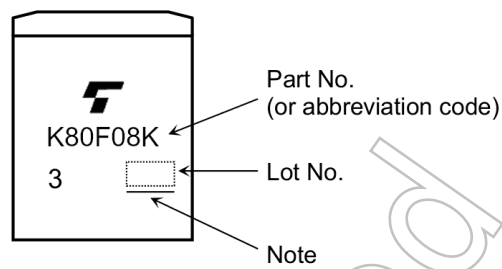


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Not Recommended for New Design

8. Moisture-Proof Packing

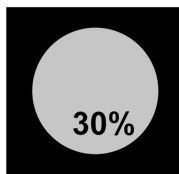
This device is packed in a moisture-proof laminated aluminum bag.

8.1. Precautions for Transportation and Storage (Note)

- (1) Avoid excessive vibration during transportation.
- (2) Do not toss or drop the packed devices to avoid ripping of the bag.
- (3) After opening the moisture-proof bag, the devices should be assembled within two weeks in an environment of 5°C to 30°C and RH70% or below. Perform reflow at most twice.
- (4) The moisture-proof bag may be stored unopened for up to 24 months at 5°C to 30°C and RH90% or below.
- (5) If, upon opening the bag, the moisture indicator card shows humidity of 30% or above (the color of the 30% dot has changed from blue to pink) or the expiration date has passed, the devices should be baked as follows:

Baking conditions: 125°C for 48 hours.

Note: Since the tape materials are not heat-proof, devices should be placed on either heat-proof trays or aluminum magazines when baking.



The humidity indicator shows an approximate ambient humidity at 25 °C. If the ambient humidity is below 30 %, the color of all the indicator dots is blue. If, upon opening the bag, the color of the 30 % dot has changed from blue to pink, the devices should be baked before assembly.

Fig. 8.1.1 Humidity Indicator

9. Characteristics Curves (Note)

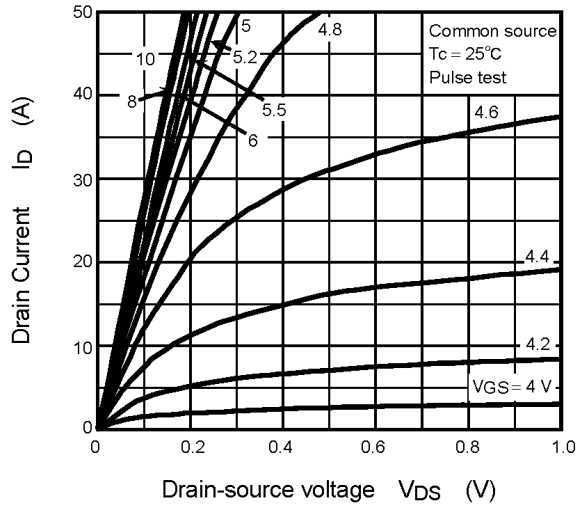


Fig. 9.1 $I_D - V_{DS}$

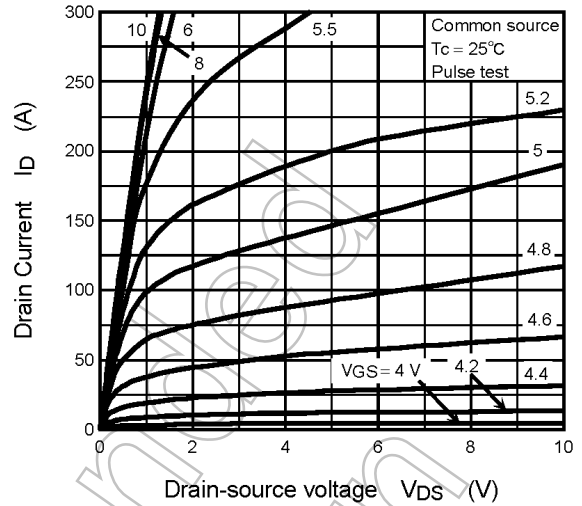


Fig. 9.2 $I_D - V_{DS}$

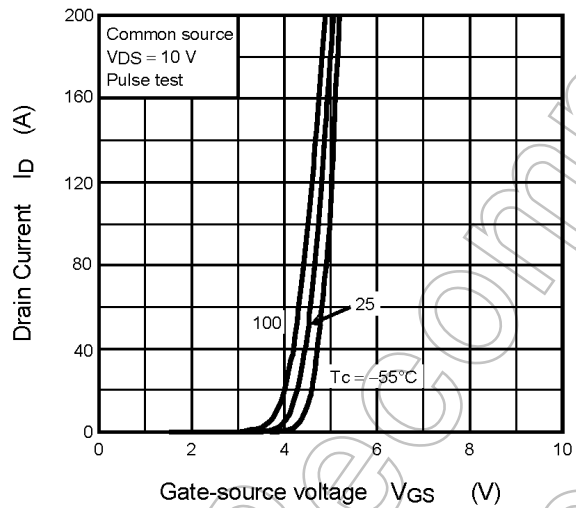


Fig. 9.3 $I_D - V_{GS}$

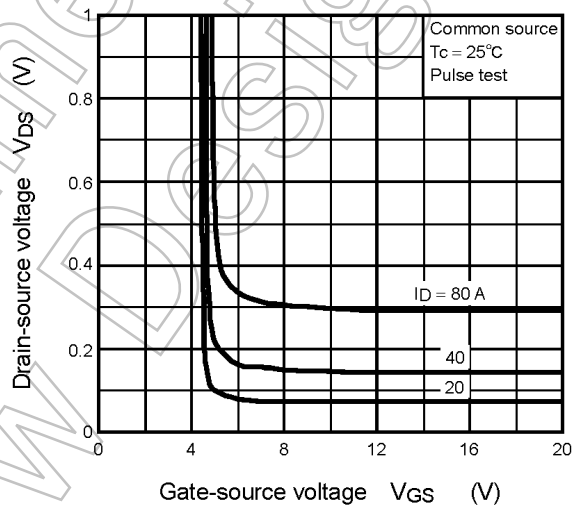


Fig. 9.4 $V_{DS} - V_{GS}$

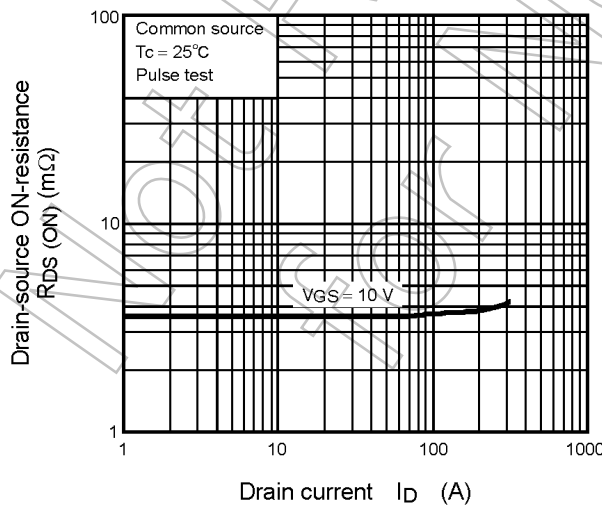


Fig. 9.5 $R_{DS(ON)} - I_D$

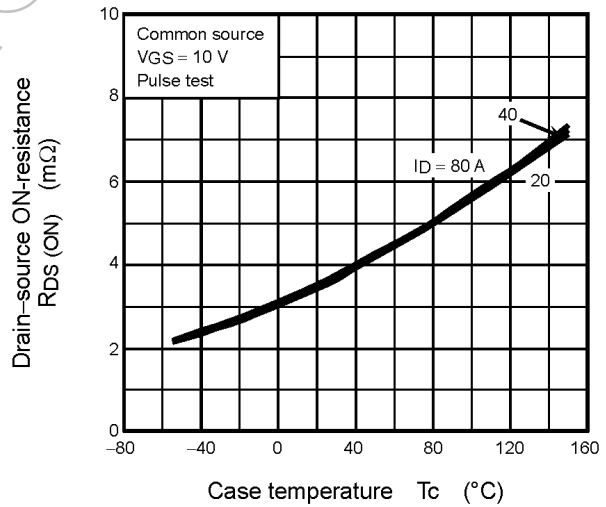


Fig. 9.6 $R_{DS(ON)} - T_c$

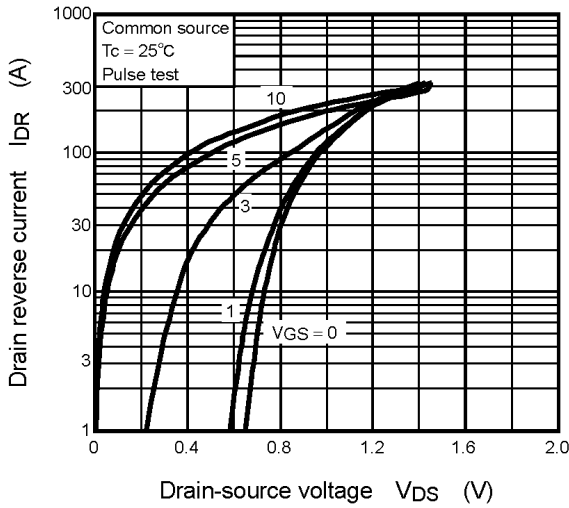


Fig. 9.7 $I_{DR} - V_{DS}$

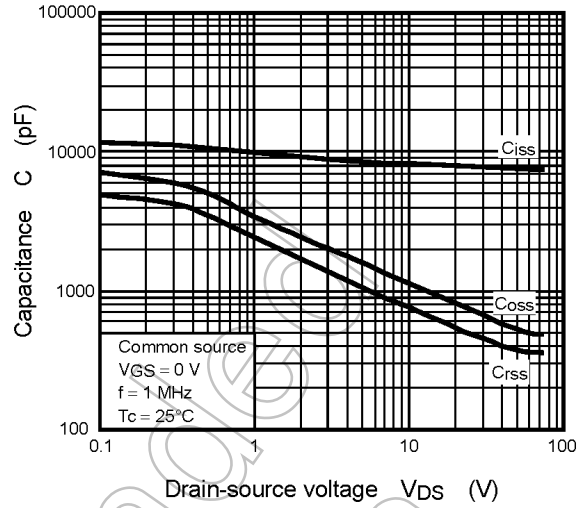


Fig. 9.8 Capacitance - V_{DS}

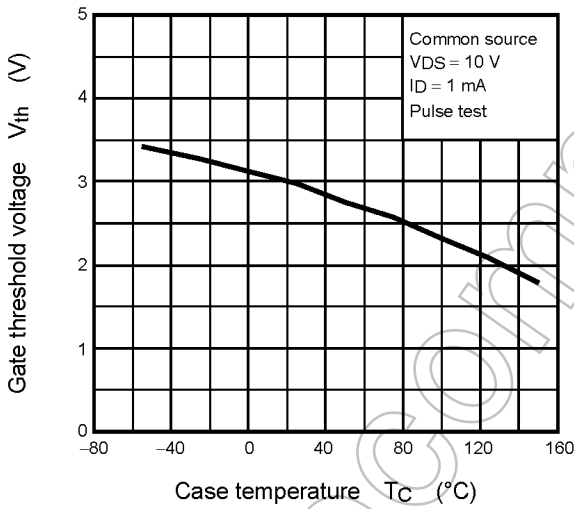
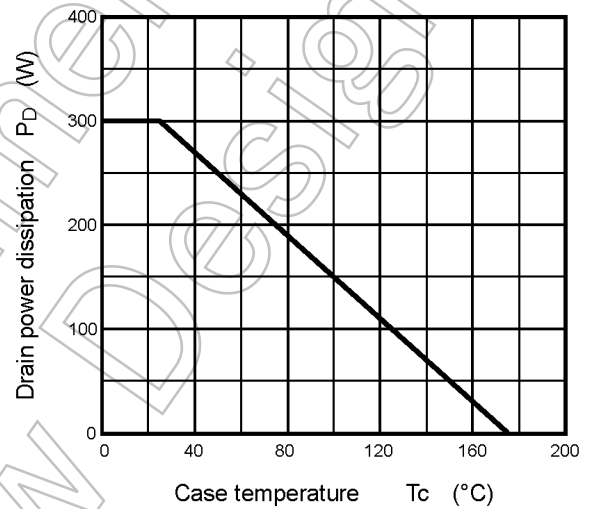


Fig. 9.9 $V_{th} - T_c$



**Fig. 9.10 $P_D - T_c$
(Guaranteed Maximum)**

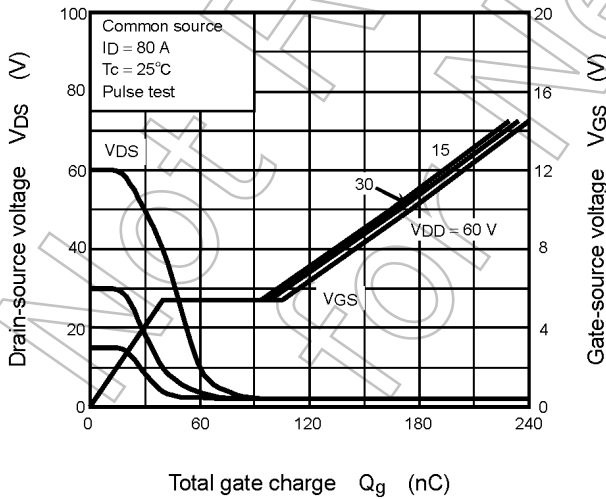


Fig. 9.11 Dynamic Input/Output Characteristics

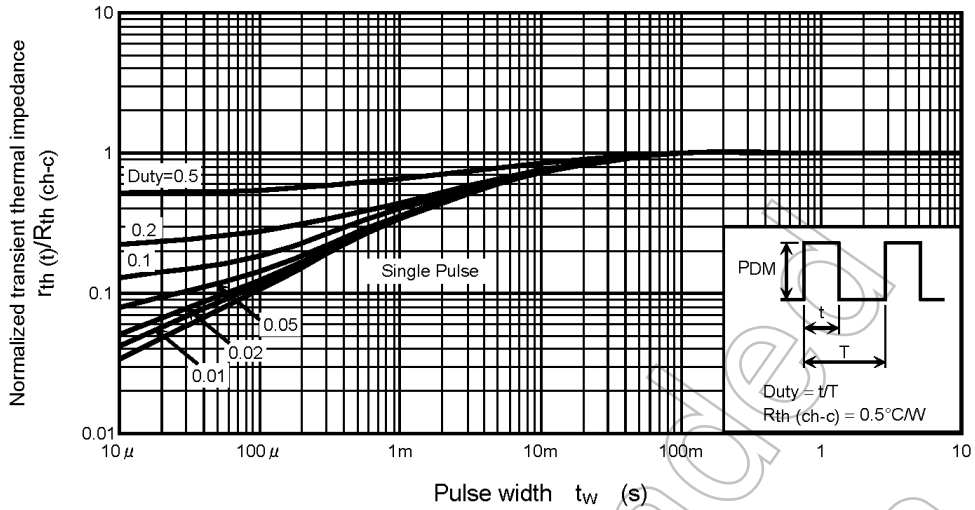


Fig. 9.12 $r_{th}/R_{th}(ch-c) - t_w$
(Guaranteed Maximum)

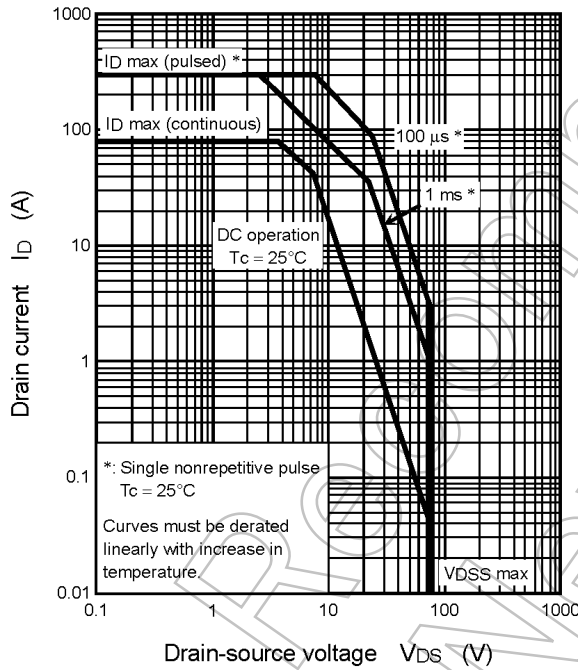


Fig. 9.13 Safe Operating Area
(Guaranteed Maximum)

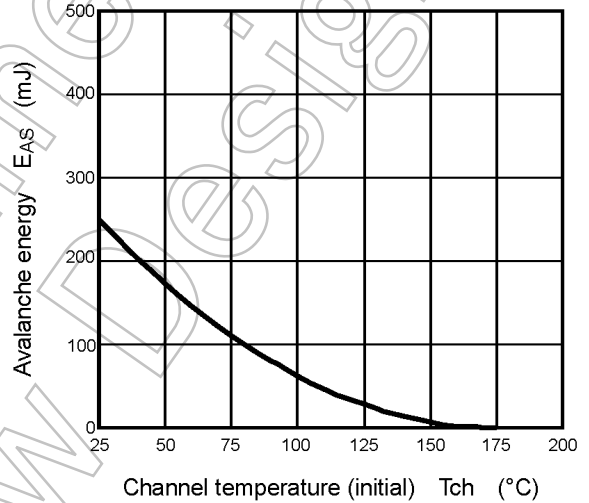
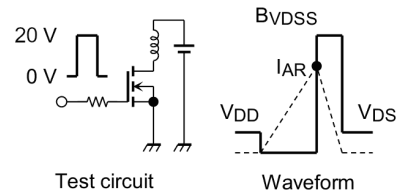


Fig. 9.14 $E_{AS} - T_{ch}$
(Guaranteed Maximum)



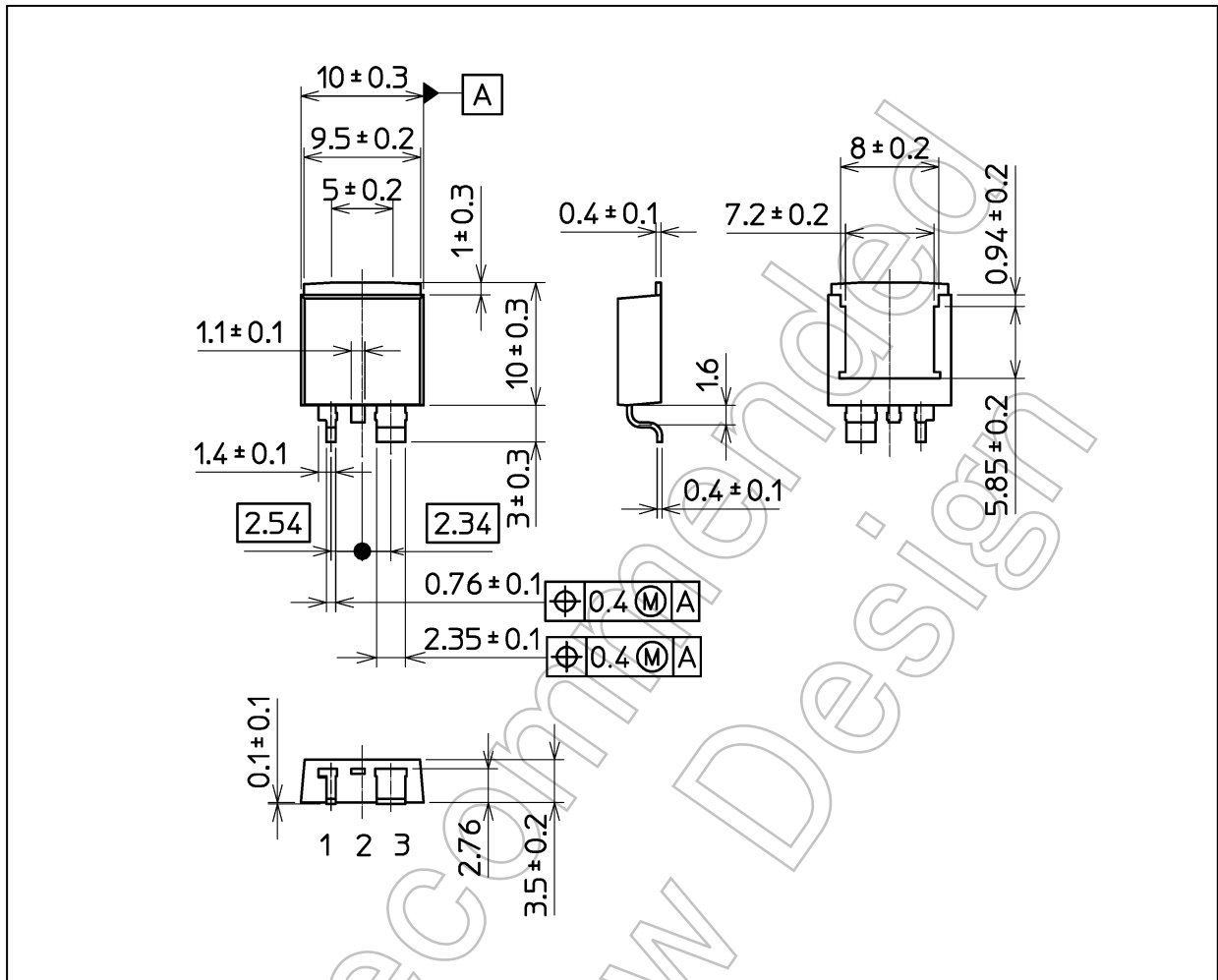
$$R_G = 1 \Omega, V_{DD} = 25 \text{ V}, L = 58 \mu\text{H} \quad E_{AS} = \frac{1}{2} \cdot L \cdot I_{AR}^2 \cdot \left(\frac{BV_{DSS}}{BV_{DSS} - V_{DD}} \right)$$

Fig. 9.15 Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 1.07 g (typ.)

| Package Name(s) |
|-----------------------|
| TOSHIBA: 2-10W1S |
| Nickname: TO-220SM(W) |

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